











CSD19538Q3A

SLPS583-MAY 2016

CSD19538Q3A 100 V N-Channel NexFET™ Power MOSFET

Features

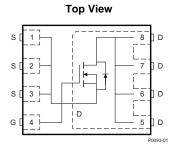
- Ultra-Low Qa and Qad
- Low Thermal Resistance
- Avalanche Rated
- Lead Free
- **RoHS Compliant**
- Halogen Free
- SON 3.3-mm × 3.3-mm Plastic Package

Applications

- Power Over Ethernet (PoE)
- Power Sourcing Equipment (PSE)
- Motor Control

Description 3

This 100-V, 49-m Ω , SON 3.3-mm × 3.3-mm NexFET™ power MOSFET is designed to minimize conduction losses and reduce board footprint in PoE applications.



R_{DS(on)} vs V_{GS} 200 $T_C = 25^{\circ}C, I_D = 5 A$ $T_C = 125^{\circ}C, I_D = 5 A$ 180 $R_{DS(on)}$ - On-State Resistance $(m\Omega)$ 160 140 120 100 80 60 40 20 0 10 12 14 V_{GS} - Gate-to-Source Voltage (V) D007

Product Summary

$T_A = 25^\circ$	С	TYPICAL VA	UNIT			
V_{DS}	Drain-to-Source Voltage	ige 100				
Q_g	Gate Charge Total (10 V)	4.3	nC			
Q_{gd}	Gate Charge Gate to Drain	0.8	nC			
0	Drain-to-Source On-Resistance	V _{GS} = 6 V	58	mΩ		
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = 10 V	49	mΩ		
V _{GS(th)}	Threshold Voltage 3.2					

Device Information⁽¹⁾

DEVICE	MEDIA	QTY	PACKAGE	SHIP
CSD19538Q3A	13-Inch Reel	3000	SON	Tape and
CSD19538Q3AT	7-Inch Reel	250	3.3-mm x 3.3-mm Plastic Package	Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	5°C	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	100	٧
V_{GS}	Gate-to-Source Voltage	±20	٧
	Continuous Drain Current (Package Limited)	15	Α
I_D	Continuous Drain Current (Silicon Limited), T _C = 25°C	14	Α
	Continuous Drain Current ⁽¹⁾	4.9	Α
I_{DM}	Pulsed Drain Current ⁽²⁾	37	Α
n	Power Dissipation ⁽¹⁾	2.8	W
P_D	Power Dissipation, T _C = 25°C	23	W
T _J , T _{stg}	Operating Junction Temperature, Storage Temperature	-55 to 150	°C
E _{AS}	Avalanche Energy, Single Pulse I_D = 12.7 A, L = 0.1 mH, R_G = 25 Ω	8.1	mJ

- (1) Typical $R_{\theta JA} = 45^{\circ} \text{C/W}$ on a 1-in², 2-oz Cu pad on a 0.06 in
- (2) Max $R_{\theta JC} = 5.5$ °C/W, pulse duration \leq 100 μ s, duty cycle \leq

Gate Charge

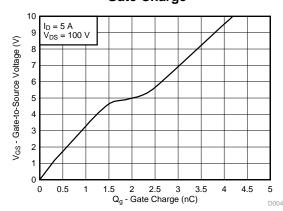






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4 Revision History

DATE	REVISION	NOTES
May 2016	*	Initial release.

Product Folder Links: CSD19538Q3A



5 Specifications

5.1 Electrical Characteristics

 $T_{\Lambda} = 25^{\circ}C$

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	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS					
BV _{DSS}	Drain-to-source voltage	V _{GS} = 0 V, I _D = 250 μA	100			V
I _{DSS}	Drain-to-source leakage current	V _{GS} = 0 V, V _{DS} = 80 V			1	μΑ
I _{GSS}	Gate-to-source leakage current	V _{DS} = 0 V, V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.8	3.2	3.8	V
<u> </u>	Dunin to common or unsistence	V _{GS} = 6 V, I _D = 5 A		58	72	mΩ
R _{DS(on)}	Drain-to-source on-resistance	V _{GS} = 10 V, I _D = 5 A		49	59	mΩ
9 _{fs}	Transconductance	V _{DS} = 10 V, I _D = 5 A		6.1		S
DYNAMI	IC CHARACTERISTICS		,			
C _{iss}	Input capacitance			349	454	pF
C _{oss}	Output capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 50 \text{ V}, f = 1 \text{ MHz}$		69	90	pF
C _{rss}	Reverse transfer capacitance			12.6	16.4	pF
R _G	Series gate resistance			4.6	9.2	Ω
Qg	Gate charge total (10 V)			4.3		nC
Q _{gd}	Gate charge gate to drain			0.8		nC
Q _{gs}	Gate charge gate to source	$V_{DS} = 50 \text{ V}, I_{D} = 5 \text{ A}$		1.6		nC
Q _{g(th)}	Gate charge at V _{th}			1		nC
Q _{oss}	Output charge	V _{DS} = 50 V, V _{GS} = 0 V		12.3		nC
t _{d(on)}	Turn on delay time			5		ns
t _r	Rise time	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V},$		3		ns
t _{d(off)}	Turn off delay time	$I_{DS} = 5 \text{ A}, R_G = 0 \Omega$		7		ns
t _f	Fall time			2		ns
DIODE C	CHARACTERISTICS				'	
V _{SD}	Diode forward voltage	I _{SD} = 5 A, V _{GS} = 0 V		0.85	1	V
Q _{rr}	Reverse recovery charge	$V_{DS} = 50 \text{ V}, I_F = 5 \text{ A},$		94		nC
t _{rr}	Reverse recovery time	di/dt = 300 A/µs		32		ns

5.2 Thermal Information

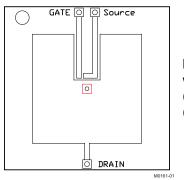
 $T_A = 25$ °C (unless otherwise stated)

	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-case thermal resistance (1)			5.5	°C/W
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾			55	°C/W

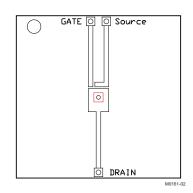
 ⁽¹⁾ R_{θJC} is determined with the device mounted on a 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu pad on a 1.5-in x 1.5-in (3.81-cm x 3.81-cm), 0.06-in (1.52-mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.
 (2) Device mounted on FR4 material with 1-in² (6.45-cm²), 2-oz (0.071-mm) thick Cu.

Product Folder Links: CSD19538Q3A





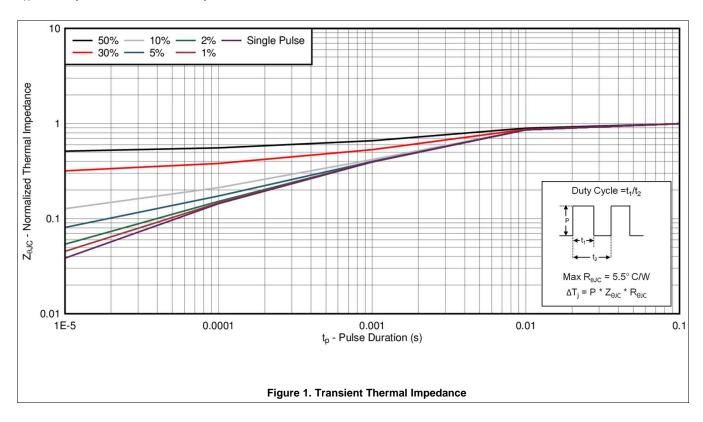
Max $R_{\theta JA} = 55^{\circ}\text{C/W}$ when mounted on 1 in² (6.45 cm²) of 2-oz (0.071-mm) thick Cu.



Max $R_{\theta JA} = 195 ^{\circ} C/W$ when mounted on a minimum pad area of 2-oz (0.071-mm) thick Cu.

5.3 Typical MOSFET Characteristics

 $T_A = 25$ °C (unless otherwise stated)



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Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)

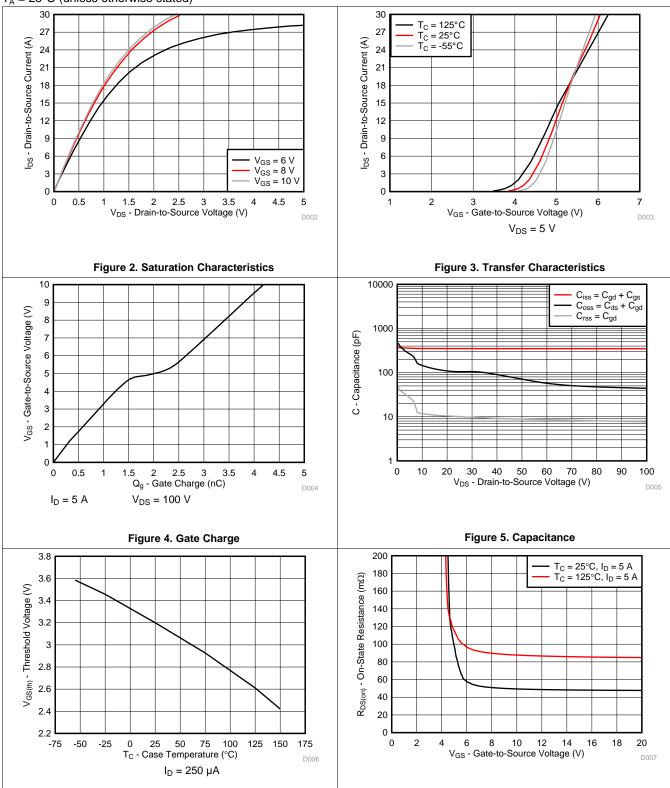


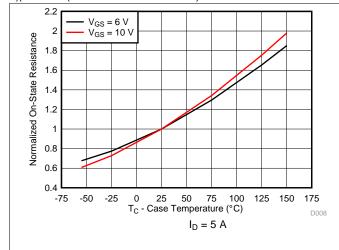
Figure 6. Threshold Voltage vs Temperature

Figure 7. On-State Resistance vs Gate-to-Source Voltage

ISTRUMENTS

Typical MOSFET Characteristics (continued)

 $T_A = 25$ °C (unless otherwise stated)



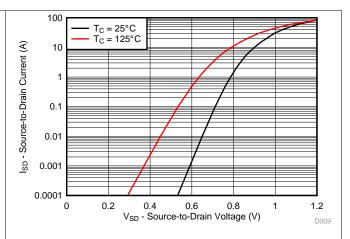
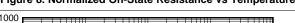


Figure 8. Normalized On-State Resistance vs Temperature



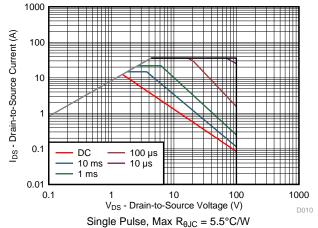


Figure 9. Typical Diode Forward Voltage

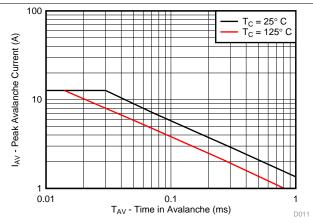


Figure 10. Maximum Safe Operating Area



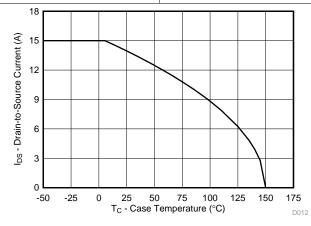


Figure 12. Maximum Drain Current vs Temperature



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6 Device and Documentation Support

6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.2 Trademarks

NexFET, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

Product Folder Links: CSD19538Q3A

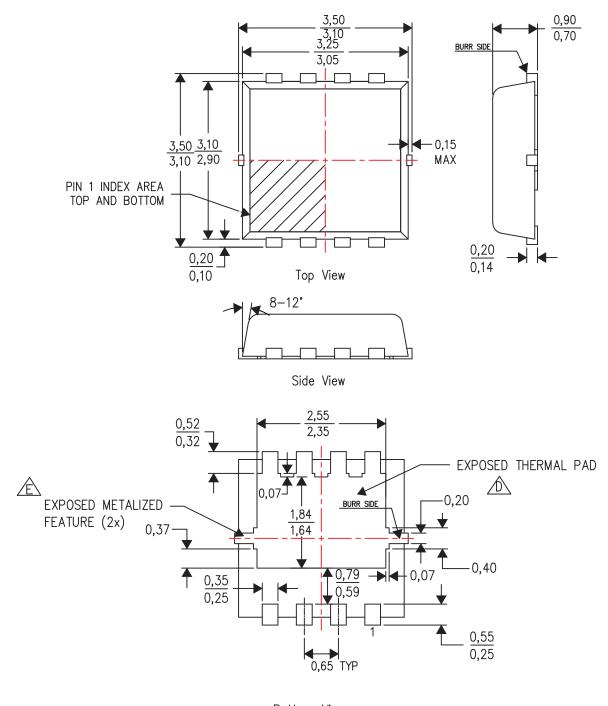
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TEXAS INSTRUMENTS

7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q3A Package Dimensions

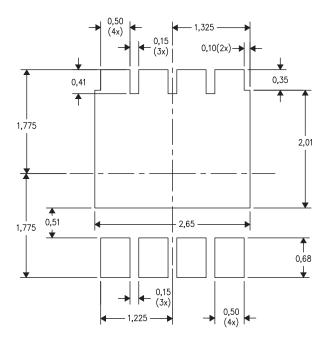


Bottom View

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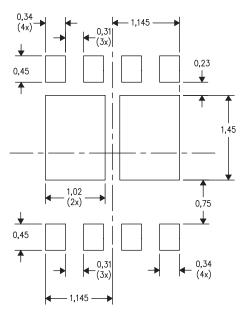
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7.2 Q3A Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

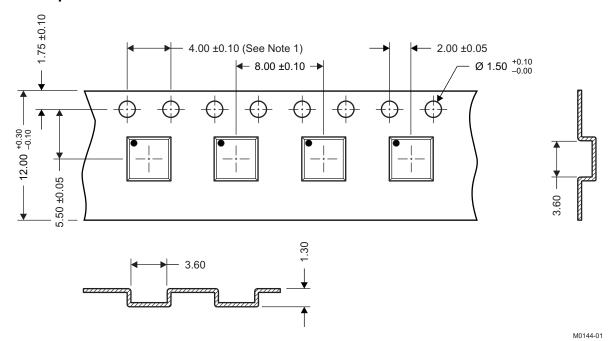
7.3 Q3A Recommended Stencil Pattern



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TEXAS INSTRUMENTS

7.4 Q3A Tape and Reel Information



Notes: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2

- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm, unless otherwise specified.
- 5. Thickness: $0.30 \pm 0.05 \text{ mm}$
- 6. MSL1 260°C (IR and convection) PbF-reflow compatible

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PACKAGE OPTION ADDENDUM

1-Jun-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD19538Q3A	ACTIVE	VSONP	DNH	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 150	19538	Samples
CSD19538Q3AT	ACTIVE	VSONP	DNH	8	250	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 150	19538	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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